M easurements of surface impedance of superconductors as a function of frequency in microwave range

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W e report m easurements of the complex resistivity in YBCO and MgB₂ thin lms over a continuous frequency spectrum in the microwave range, making use of a Corbino disk geometry. The paper mainly focuses on the extraction of the resistivity from raw data, displaying data analysis procedure and its limits of validity. W e obtain and show resistivity curves as a function of frequency and temperature denoting a frequency dependent widening of the superconducting transition.

I. IN TRODUCTION

The m icrow ave response of superconductors is of great interest in several temperature and m agnetic eld ranges, since it carries inform ation about both m acroscopic and m icroscopic quantities, such as resistivity or electrom agnetic penetration depth.

M ost of available experimental data are restricted to xed frequencies (resonant cavity techniques), whereas a study over a continuous frequency spectrum would allow for a deeper investigation of the dynamical behaviour of the system. An experimental technique which makes it possible to evaluate the complex surface impedance $Z_s = R_s + iX_s$ of a superconducting lm as a function of frequency has been proposed in the past by some groups [1, 2]. The technique is based on the measurement of the rejection coe cients at the input of a coaxial line term inated by the lm (C orbino disk).

Extracting the contribution of the sam ple from the measured data is a critical step during data analysis: the contribution of the coaxial line, in fact, is in general comparable with that of the sam ple. The main purpose of this paper is to present the most recent results on this experimental procedure, as obtained in our laboratory.

II. EXPERIMENTAL SETUP

Tem perature is varied employing a helium ow cryostat and magnetic eld is generated by a superconducting coil (maximum attainable eld: 16 T). The electrom agnetic eld is generated and analysed by a Vector N etw ork A nalizer (VNA), connected to the sam ple by a commercial coaxial cable (cuto frequency: 60 G H z), about 3.5 m eters long (1 m eter inside the cryostat and 2.5 m eters outside). Such a large distance is needed in order to keep the VNA as far as possible from the magnet. On the other hand such a high length results in a heavy attenuation of the signal, especially at higher frequencies, which prevented us to perform measurem ents above 35 G H z and resulted in highly noisy measurem ents above 20 G H z.

The sample surface in pedance is probed as a function of frequency through a Corbino disk geometry, in which the sample shortcircuits the above mentioned cable. The connection between the cable and the sample is realised through a double spring method, extensively described in [2]. With respect to previous realisations, a thin indium ring has been placed between the sample and the outer connector of the cable, to reduce the possible damage of the sample. However this was not su cient to suppress a detectable contact capacitance. The capacitance e ect results to be smaller for the M gB₂ lm than for the YBCO lm, suggesting that the sample surface plays a relevant role in the overall contact realisation. As a result of this spurious capacitance, data on YBCO are not reliable below 6 G H z, while in the case of M gB₂ the capacitance m asks data only below 2 G H z, so that the actual frequency range over which measurements will be presented in the following of the paper is limited to 6 20 G H z for YBCO and 2 20 G H z for M gB₂.

The samples here considered are a thin (d' 2200 A), square (l = 10 mm) YBCO m, grown by planar high oxygen pressure DC sputtering on a LaA lO₃ substrate [3], and a thin (d' 1500 A), square (l = 5 mm) MgB₂ m, grown by pulsed laser deposition with a conventional two step technique on a sapphire substrate [4].

The measured quantity is, for any magnetic eld H and temperature T, the rejection coecient $_m$ (;T;H), measured at the VNA location. Two kinds of measurements can be made during a measuring session: the collection of a set of curves $_m$ (;T;H₀) at xed magnetic eld and di erent temperatures, to which we will refer in the following as \transitions", or the collection of a set of curves $_m$ (;T;H) at di erent magnetic elds and xed temperature, which will be called $\$ eld sweeps". The dependencies on ;T;H will be often om itted in the following for the sake of compactness.

III. M EASUREMENT TECHNIQUE

As discussed in the introduction, the problem issued in this paper is how to extract the surface impedance $Z_s()$ of the sample from the rejection coeccients m() measured at the beginning of the coaxial cable. $Z_s()$ is defined as the ratio between transverse electric and magnetic eld components at the sample surface.

It is possible to demonstrate [1, 2] that $Z_s()$ is related to the rejection coeccient at the sample surface $_0()$ through the relation

$$Z_{s}() = Z_{0} \frac{1 + 0}{1 + 0} ()$$
(1)

where Z_0 is the characteristic in pedance of the dielectric lling the cable. We estimate $Z_0 = 377$ (vacuum in pedance) being the last section of the cable not led with the dielectric.

In principle, the values of $_0$ () can be extracted from the measured rejection coeccient at the VNA input $_m$ () through the standard relation [6]

$$m = E_{d} + \frac{E_{r} 0}{1 - E_{s} 0}$$
(2)

where E_r , E_s and E_d are complex error coeccients taking into account distortions of the signal due to the transmission through the cable. They depend on frequency and on the temperature proce of the whole cable but we want to stress since now that, since the cable is constructed with non magnetic materials, the error coeccients do not depend on magnetic eld. These three parameters are custom arily determined by measuring the response of three known loads replacing the sample (line calibration) but in our case the experimental setup does not allow for a full calibration of the cable since the Corbino cell is inaccessible during measuring sessions and calibration standards at the temperatures of interest in this work are not available. Nevertheless extraction of useful information from the experimental data is possible through the following two step procedure.

First step: de nition of $\boldsymbol{e}_{\scriptscriptstyle m}$ () and its main features

D aily calibration of the section of the cable external to the cryostat was perform ed, hence from here on we will no further consider it, as if the VNA were directly connected to the internal, one meter long, cable. This means that the cable and re ection coe cients dealt with in the following are only relative to the internal cable.

Before the beginning of the experiment we measured and stored the error ∞e cients E_r , E_s and E_d of the internal cable at room temperature T_r . We then de ne^e_m (;T) as:

$$e_{m}(;T) = \frac{m(;T) - E_{d}(;T_{r})}{E_{r}(;T_{r}) + E_{s}(;T_{r})(m(;T) - E_{d}(;T_{r}))}$$
(3)

As can be seen by inverting equation 2 with respect to $_0(), e_m()$ is $_0()$ when measured at $T = T_r$ and at all the other temperatures if the error coe cients were temperature independent. A relation between $e_m(;T)$ and $_0(;T)$ at $T < T_r$, can be found if we put $_m(;T)$ as obtained from equation 2 into equation 3:

$${}_{0}(T) = \frac{E_{d}(T_{r}) - E_{d}(T) + \frac{E_{r}(T_{r})e_{m}(T)}{1 - E_{s}(T_{r})e_{m}(T)}}{E_{r}(T) + E_{s}(T) - E_{d}(T_{r}) - E_{d}(T) + \frac{E_{r}(T_{r})e_{m}(T)}{1 - E_{s}(T_{r})e_{m}(T)}}$$
(4)

We expect cable coe cients not to change by m ore than 10% for any variation of the tem perature prode in the cable. Moreover, during the room tem perature calibrations, we found \mathbf{F}_{d} j and \mathbf{F}_{s} j to be quite generally no m ore than 10%

of $\mathbf{E}_r \mathbf{j}$ which is instead of the same order of $\mathbf{f}_m \mathbf{j'}$ 1. This means that $\mathbf{E}_d(\mathbf{I}_r) = \mathbf{E}_d(\mathbf{I})\mathbf{j'}$ 10² $\mathbf{E}_r \mathbf{e}_m$ jand we can neglect it in equation 4, obtaining after some algebra

$${}_{0}' \frac{\frac{E_{r}(T_{r})}{E_{r}(T)}e_{m}}{1+e_{m}E_{s}(T)[E_{s}-E_{r}]}$$
(5)

Where $E_{s;r} = (E_{s;r}(T)) = E_{s;r}(T)$. Again $E_s e_m ' 0:1$ and $E_{s;r} ' 0:1$ so that one gets, to within a few percent of precision,

$$_{0} \prime \frac{E_{r}(T_{r})}{E_{r}(T)} e_{m} \stackrel{:}{=} \frac{e_{m}}{(T)}$$
(6)

We stress that the coe cient (;T), de ned through equation 6, depends in a non-trivial way upon the whole tem perature pro le of the cable so that no practical measurem ent of it is possible. Nevertheless, when performing measurem ents at low T (T < 100K), it is reasonable to expect that it is almost constant when varying the tem perature of the sam ple of a few tens of K elvin; the cable, in fact, is therm ally constrained at room temperature at the entrance of the sam ple of a few tens of K elvin; the cable, in fact, is therm ally constrained at room temperature at the entrance of the sam ple [7]. If this is the case, though e_m () is essentially di erent from $_0$ (), the ratios of e_m () are good approximations of the ratios of the corresponding $_0$ (). It is worth to note that equation 6 is a relation between com plex quantities, im plying the follow ing couple of real equations:

A swe will see, while j j is reasonably constant over sm all variations of tem perature, the same does not hold generally for A rg[]. This poses some lim it to the know ledge of $A rg[_0]$, the consequences of which will be discussed in the follow ing.

Second step: obtaining variations of $\rm Z_{\,s}$ ()

In this paragraph we will demonstrate how the ratio of two $_0$ () determ ined at two dimensions are needed which we magnetic elds is related to the corresponding dimension of impedances. Some approximations are needed which we will discuss in the next section. We are consider only temperature variations and then we will extend our conclusions to the case of varying magnetic eld.

Let's consider the di erence between two curves of Z_s () at two di erent values of the tem perature, say T_1 and T_2 . M aking use of equation 1, we can write

$$Z_{s}(;T_{1};T_{2}) \stackrel{:}{=} Z_{1}(;T_{1}) \quad Z_{2}(;T_{2}) = Z_{0} \frac{1 + 0(;T_{1})}{1 + 0(;T_{1})} \frac{1 + 0(;T_{2})}{1 + 0(;T_{2})} \frac{1 + 0(;T_{2})}{1 + 0(;T_{2})} = Z_{0} \left(\frac{1 - \frac{0(;T_{1})}{0(;T_{2})}}{1 + \frac{0(;T_{1})}{0(;T_{2})}} \frac{(1 + 0(;T_{1}))(1 + 0(;T_{2}))}{2 + 0(;T_{2})}} \right) A$$

$$(7)$$

The approximation involved in the last equivalence will be extensively discussed in the following, but we stress since now that it is surely possible if $_0(;T_2)'$ 1. Within this limit we then found that the dimension between two values of the impedance at dimension perature is a function only of the ratio of the respective remetion comments at the sample surface. We can separate the above equation in its real and imaginary part, in order to work with real rather than complex quantities. Writing as usual $Z_s \doteq R_s + iX_s$, we have

$$R_{s}(;T_{1};T_{2}) = Z_{0} \frac{1 \frac{j_{0}(;T_{1})}{j_{0}(;T_{2})} f}{1 + j_{0}(;T_{1})} f + 2Re[\frac{0}{0}(;T_{1})]}$$
(8)

$$X_{s}(;T_{1};T_{2}) = 2Z_{0} \frac{\operatorname{Im}\left[\frac{0}{0}(;T_{1})\right]}{1 + j\frac{0}{0}(;T_{2})} + 2Re\left[\frac{0}{0}(;T_{1})\right]}$$
(9)

Now we come to the last approximation. We define $0() = Arg[0(;T_1)] Arg[0(;T_2)]$ as the phase variation between the two rejection coefficients; if 0() is small (for each frequency ()) of interest) then the approximations $R = \frac{0(;T_1)}{0(;T_2)} - \frac{0(;T_1)}{0(;T_2)}$ and $Im = \frac{0(;T_1)}{0(;T_2)} - \frac{0(;T_1)}{0(;T_2)} - \frac{0(;T_1)}{0(;T_2)} - 0$ hold. In this case equations 8 and 9 can be approximated as

$$R_{s}(;T_{1};T_{2})' Z_{0} \frac{1}{1+j_{0}(;T_{1})} \frac{j_{0}(;T_{1})}{1+j_{0}(;T_{2})} j$$
(10)

$$X_{s}(;T_{1};T_{2})' = 2Z_{0} \frac{\frac{j \circ (T_{1})}{\sigma (T_{2})}j}{(1 + j \circ (T_{2}))^{2}} 0 = 0$$
(11)

where we stress that equation 10 depends only on the ratio of the moduli of the rejection coeccients and not upon the phase variations. In this way the determination of R_s requires information about $j_0 j$ only, while X_s can be obtained only through the know ledge of both $j_0 j$ and 0.

Putting the results of equation 6 into these form ulae we get

$$R_{s}(;T_{1};T_{2})' Z_{0} \frac{1}{1 + \frac{j(:T_{2})j \mathcal{P}_{m}(:T_{1})j}{j(:T_{1})j \mathcal{P}_{m}(:T_{2})j}}{1 + \frac{j(:T_{2})j \mathcal{P}_{m}(:T_{1})j}{j(:T_{1})j \mathcal{P}_{m}(:T_{2})j}}$$
(12)

$$X_{s}(;T_{1};T_{2})' 2Z_{0} \frac{\frac{j(;T_{2})j \mathcal{P}_{m}(;T_{1})j}{j(;T_{1})j \mathcal{P}_{m}(;T_{2})j}}{(1 + \frac{j(;T_{2})j}{j(;T_{1})j \mathcal{P}_{m}(;T_{2})j}} (m)$$
(13)

If we have j (;T₁)j' j (;T₂)j so that $\frac{j_0(;T_1)j}{j_0(;T_2)j}$ ' $\frac{p_m(;T_1)j}{p_m(;T_2)j}$, equation 10 can be nally rewritten as

$$R_{s}(;T)' Z_{0} \frac{1}{p_{m}(;T_{2})j} \frac{p_{m}(;T_{2})j}{1 + \frac{p_{m}(;T_{2})j}{p_{m}(;T_{2})j}}$$
(14)

If we also have

 $_{0}$, so that $_{0}$ ' $_{m}$, then equation 11 can be approximated with

$$X_{s}(;T)' = 2Z_{0} \frac{\frac{je_{m}(;T_{1})j}{je_{m}(;T_{2})j}}{(1 + \frac{je_{m}(;T_{1})j}{je_{m}(;T_{2})j})^{2}} m$$
(15)

Form ulae 14 and 15 are the main result of this paper. They relate the variation of impedance between two dimensions the measured quantities. Through these form ulae, in fact, once a temperature T_{ref} at which $_0$ ' 1 is xed, the dimensions $Z_s(;T) \stackrel{:}{=} Z_s(;T) = Z_s(;T) = Z_s(;T_{ref})$ for each temperature T can be obtained. Moreover, once all the Z_s are known, if a temperature T exists for which the curve $Z_s(;T)$ is theoretically predictable or experimentally known, absolute values of $Z_s(;T)$ can be extracted.

The procedure can be easily extended to the case of m easurements as a function of the applied magnetic eld at a xed temperature T_0 (eld sweeps). In this case, $Z_s = Z_s$ (;H) = Z_s (;H;T₀) Z_s (;H_{ref};T₀) and the values of R_s (;H) and X_s (;H) are obtained with the same expressions as in equations 14 and 15 by replacing the temperature dependence with the magnetic eld dependence. W ith respect to measurements as a function of temperature, there is the advantage that the response of the cable is not expected to vary by applying an external magnetic eld. This implies that the coe cient () remains constant among measurements at di erent magnetic

elds, provided that the whole cable has reached its equilibrium temperature prote. The result is that the condition $(;H) = (;H_{ref})$ needed to obtain equations 14 and 15 from 12 and 13 is exactly, instead of approximately, satisfied.

In this paragraph we discuss the validity of the approximations introduced in the previous section to come to equations 14 and 15. Two of these approximations deal with hypotheses on $_0$ (markedly, that it exists a pair of values fH,Tg for which $_0$ (H;T;)' 1 and that the variation of Arg[$_0$] as a function of T and H are small) while the other two approximations deal with the variation as a function of T and H of the complex parameter relating $_0$ with e_m . This task will be accomplished by putting together information that can be obtained from DC and m icrow ave measurements, as well as from theoretical predictions.

As a rst step, we notice that from the resistivity value obtained from DC m easurements (see gure 2) we can infer that the thin Im approximation [5] is valid just above the transition temperature. We will then assume that for all temperatures one may write Z_s ' =d. We then focus on the assumptions related to $_0$. The rst assumption is certainly veried at low enough temperatures and zero applied magnetic eld, since both R_s and X_s are expected to become much smaller than Z_0 for T T_c , so that $_0 = (Z_s - Z_0) = (Z_s + Z_0)$ ' 1. We will come later on the criteria used to choose the value of T_{ref} , and to the choice of H_{ref} and T_{ref} for the measurements as a function of the applied magnetic eld.

The second approximation can be veried by measuring the temperature variations of the phase of the measured e_m . In gure 3 we report the behaviour of Arg f_m] as a function of T for H = 0 T and = 17.5 GHz. The overall behaviour is composed by a rather sharp peak, located in a T range just below T_c , over a smoothly T dependent background. Since the phase of $_0$ is expected to be constant, as a function of T, both above T_c (where Z_s and thus $_0$ are real) and su ciently below T_c (where, as discussed above, $Arg[_0]'$), it is natural to ascribe the sm ooth background to variations of $Arg[_1]$ and the peak to variations of $_0$. The peak of $Arg[_0]$ can be easily understood on general grounds: in fact, $Arg[_0] \notin 0$ only if X_s is comparable with Z_0 , which is true only at temperatures slightly below T_c . Sim ilar results are obtained also when it is present an applied magnetic eld. From the measured values, one gets $_0$ 0:1 rad, so that the approximation $_0$ 1 is reasonably full led for all temperatures and elds.

We now come to the approximations dealing with the variations of , starting with the approximation j j' const. In gure 2 we plot the measured DC resistivity of the M gB₂ sample, together with the measured f_m^e j at 17.5 GHz. Since is expected to be real and independent on frequency above T_c , one has Z_s real in this temperature range, resulting in $_0$ being real and independent on frequency. Further, since $_{DC}$ is almost independent on T for 35K < T < 45K, we may conclude that $_0$ is also almost independent on T just above T_c . The measured f_m^e j is approximately constant, as a function oftem perature, between 45K and 35K, as well as below 13K. This is consistent with the above discussion: above T_c , one has $_0$ almost independent on T, and su ciently below T_c one has j $_0$ j' 1, again independent on T. The small variation as a function of T can then be ascribed to variations of j j with T, which turn out to be m uch smaller than the variations of j $_0$ j as required. It is worth to stress that at high frequency one has R_s ' 0 only for T T_c , so that it is not surprising that the condition e_m ' 1 is reached only for T ' 13K. A s noticed before, this fact, together with the validity of the assumptions on $_0$ previously verie ed, guarantees that it is possible to obtain the values of R_s from the measured $_m$.

The last approximation to be verified is the one related to variations of Arg[]. It is evident from gure 3 that the peak of $Arg[_0]$ is of the same order of magnitude as the variations of the smooth background. This means that the condition $_0$ does not hold and we cannot make use of equation 15 to get sample reactance from measurements as a function of temperature. As noticed before, this limitation is intrinsically eliminated when performing measurements at the performing measurements at the measurement of the mea

Obtaining the im pedances

Once the validity of the approximations has been discussed, we turn to the description of the practical method employed for the determination of the impedance. This purpose is pursued through extensive use of equations 14 and 15. We start with the zero eld case. First of all it is necessary to choose the reference temperature T_{ref} with respect to which we calculate the variation of the impedance. This choice is dictated by the necessity to satisfy the approximation involved in equation 7. As we saw in the previous paragraph this approximation is surely valid for the zero eld transition when the choice T_{ref} T_c is made. Operatively the condition T T_c is considered to be reached when the curves f_m^c (;T;0) japproach a constant value as a function of temperature (in gure 2, for example, below 13 K). The temperature T_{ref} is then chosen as low as possible considering that we need at the same time ' const in the temperature interval $[T_{ref};T_c]$. We then choose $T_{ref} = 4$ K for M gB₂ and $T_{ref} = 70$ K for YBCO [8].

Once we have all the di erences $R_s(;T;0) = R_s(;T;0)$ $R_s(;T_{ref};0)$ we can obtain the absolute values $R_s(;T;0)$ if one of the curves $R_s(;T;0)$ is known. Again, as we discussed in the previous paragraph, at T_c

 R_s ' 0 so that in this case the extraction of the absolute values is trivial because, with the choice of T_{ref} T_c , R_s (;T;0) = R_s (;T;0).

For whet concerns the eld sweeps measurements we chose $H_{ref} = 0$ for all sweeps. In this case, when the temperature T_0 at which the eld sweep is performed is close to T_c , the condition $_0(;T_0;H_{ref})'$ 1 is not fully satisticated. Nevertheless, by using the values of $R_s(;T;0)$ obtained from the zero eld transition, we can estimate in no more than 5% the errorm ade with the approximation contained in equation 7.

Absolute values of R_s can again be extracted for eld sweeps measurements using the curve R_s (; T_0 ;0) obtained from the zero eld transition. Since, by choosing $H_{ref} = 0$, all the curves R_s are variations with respect to H = 0, we add to all the curves of the eld sweep the curve R_s (; T_0 ;H = 0), obtained from the zero eld transition. In this way we transform the set of curves R_s (; T_0 ;H) into a set of curves R_s (; T_0 ;H).

To obtain absolute values of X_s we cannot make use of the zero eld transition because we recall that X_s cannot be extracted from transitions. However we can exploit the fact that above the upper critical eld, where the system is in the normal state, X_s is expected to vanish. Then, by subtracting to each curve $X_s(;T_0;H)$ the value of $X_s(;T_0;H)$, with $H > H_{c2}$, one gets the absolute values of $X_s(;T_0;H)$. In order to check for which values of H the condition $H > H_{c2}$ is satistic ed, we analyse the curves $X_s(;T_0;H)$ in a similar way as was done to determ ine T_{ref} in the zero eld transition: it can be noticed, in fact, that $X_s(;T_0;H)$ approaches a constant value at high magnetic elds, so that we choose H among the elds at which $X_s(;T_0;H)'$ const.

This latter procedure is possible only if the observed $X_s(;T_0;H)$ reaches a constant value at high elds, that is if the applied magnetic eld reaches a value above the upper critical eld. This can easily be obtained M gB₂, whose upper critical eld is around 10 T even at low tem perature, while it is not possible for YBCO, whose upper critical eld exceeds our experimental limits a few K elvin below T_c . The results will then be presented as $R_s(;T;H)$ and $X_s(;T;H)$ for M gB₂, while for YBCO we can report only $R_s(;T;H)$ and $X_s(;T;H)$.

IV. RESULTS

In the following, we report some examples of the measuring procedure for both M gB₂ and YBCO.We ext present the results of the measurement at zero magnetic eld as a function of temperature. In g. 4 we report the real part of $Z_s(T)$ in M gB₂ at dimension of the transition widens with increasing frequency. To have a more quantitative description of the widening, one can de ne $T_{m p}()$ as the temperature where the resistivity, at the given frequency , reaches one half of the value in the normal state, and $T_c() = T_{m p}() T_{n p}(m in)$. The behaviour of $T_c()$, normalised to the value of T_c at m in = 2 GHz is reported in g. 6 (led circles).

The same analysis is presented in g.5, for YBCO where curves of $R_s=R_s(100K)$ are presented as a function of T at various frequencies. The real part of the resistivity remains almost zero up to '88 K, then grows at T_c rapidly reaching the norm alstate value. As in the case of MgB₂, the transition widens as the frequency is increased. However, the widening is relatively small compared to MgB₂ and the upper part of the transition is almost una ected by the variation of the frequency, being only the very last part of it severely dependent on frequency. The values of $T_c=T_c$ (with $m_{in} = 6 \text{ GHz}$) are reported in g.6 for a quantitative comparison with the values obtained for MgB₂.

We now come to the results as a function of magnetic eld, at xed frequency. Again, we rst present results on $M gB_2$. In gure 7 we report measurements of $R_s = R_n$ and $X_s = R_n$ (where R_n is the resistivity at the highest eld) at 7.5 K and di erent frequencies, as a function of the applied magnetic eld. Both R_s (upper panel) and X_s (low er panel) do not show appreciable variations as a function of eld above $_0H$ ' 9 T, indicating that the upper critical eld is reasonably below that value. The assumption that at 13 T them aterial is in its norm alstate, so that R_s (;13T) = R_n and X_s (;13T) = 0 is then fully justiled. Finally, we present in gure 8 the real part of the resistivity in YBCO at T = 80 K, at various frequencies and as a function of the applied magnetic eld.

V. CONCLUSIONS

We collected rejection coe cient measurements of superconducting thin in s as a function of frequency through a Corbino disk technique. We developed a measurement technique by which it is possible to obtain the impedance from the rejection coe cients once that some conditions are veriled. We extensively discuss these conditions and how we can conclude which of them are veriled. The relative curves at is the frequencies are shown, together with a brief discussion of the data.

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- [6] R E Collin, Foundation for m icrowave engineering M cG raw H ill (1966)
- [7] We can also roughly estimate the frequency dependence of (;T) considering that it is the ratio between two transmission coecients at dierent temperatures. Since E $_r(;T)$ takes into account the attenuation of the eld due to losses through the dielectric and on the cable conductors, it decreases with increasing frequency and temperature. We can then expect that, if $T < T_r$, j (;T) j> 1 and it will increase with frequency. This is exactly the behaviour measured, as can be seen in gure 1.
- [8] Since the condition $_0$ ' 1 is more and more satisfied as T $_{c}$, one might be tempted to use T = 4 K for both YBCO and MgB₂. However, an important requirement is that be constant over the whole T range between T_{ref} and the temperature T of interest. It is the necessary to limit the overall temperature range explored, in order to minim ise the elects of temperature variations of .

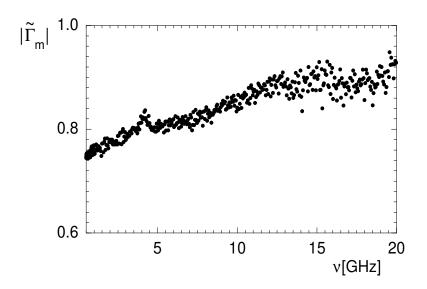


FIG.1: Typical curve of \mathcal{P}_m j(;T) at xed tem perature T = 40K as a function of frequency for M gB₂. Since j₀ j is reasonably constant with frequency at this tem perature we attribute the frequency dependence of \mathcal{P}_m j(;40K) to a frequency dependence in j (;40K) j.

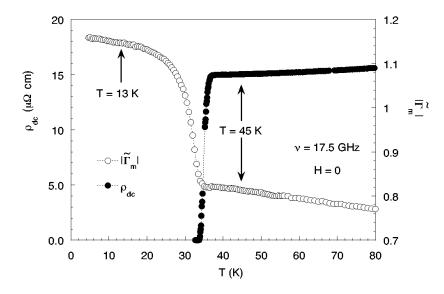


FIG. 2: Right-hand scale, empty circles: modulus of e_m (;T) at xed frequency = 17:5 GHz as a function of temperature and zero magnetic eld. Left-hand scale, full circles: DC resistivity of the same sample at zero eld.

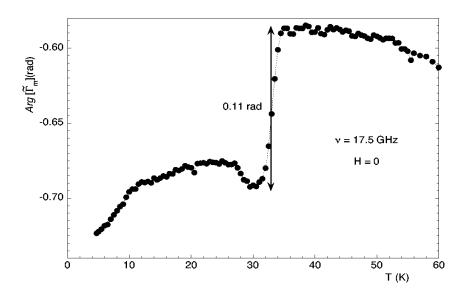


FIG.3: Phase of e_m (;T) at xed frequency = 17:5 GHz as a function of tem perature and xed zero feld for M gB₂.

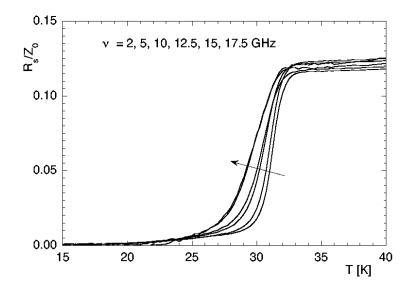


FIG.4: M easured resistivities as a function of tem perature, at several xed frequencies. Note the widening of the transition, as the frequency is increased.

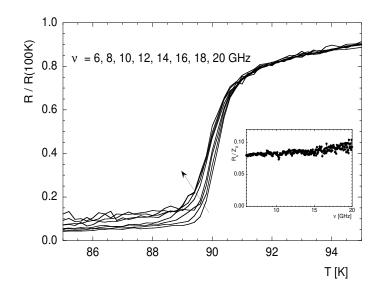


FIG.5: M easured resistivities as a function of tem perature for the YBCO lm. The resistivities has been normalized to their value obtained at 100 K to reduce the e ect of the variation of the cable parameters between 70 and 100 K. The behaviour of R_s at 100 K is reported in the insert.

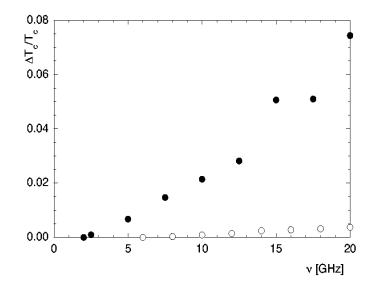


FIG.6:W idening of the transition as a function of frequency, for both YBCO (open symbols) and MgB₂ (lled symbols) (see text for the de nition of T $_c$ =T $_c$)

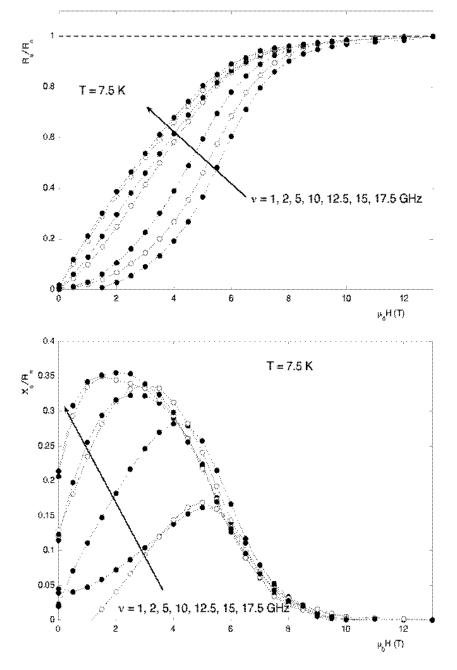


FIG.7: M easurement of R_s (upper panel) and X_s (lower panel) in M gB₂ at T = 7.5K and various frequencies, as a function of the applied magnetic eld.

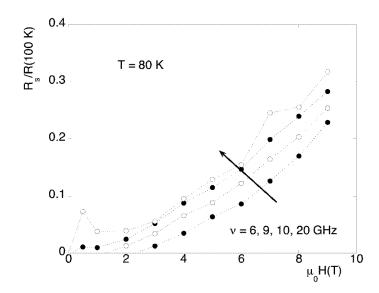


FIG.8: M easurement of R_s in YBCO at T = 80K and various frequencies, as a function of the applied magnetic eld.